

Abstracts

A W-Band Monolithic Low Noise AlGaAs/InGaAs Pseudomorphic HEMT Amplifier Mounted on a Small Hermetically-Sealed Package with Waveguide Interface (1995 Vol. I [MWSYM])

Y. Itoh, M. Nakayama, K. Nakahara, T. Takagi, T. Sakura, N. Yoshida, T. Katoh, T. Kashiwa and Y. Ito. "A W-Band Monolithic Low Noise AlGaAs/InGaAs Pseudomorphic HEMT Amplifier Mounted on a Small Hermetically-Sealed Package with Waveguide Interface (1995 Vol. I [MWSYM])." 1995 MTT-S International Microwave Symposium Digest 95.1 (1995 Vol. I [MWSYM]): 207-210.

A W-band monolithic low noise AlGaAs/InGaAs/ GaAs pseudomorphic HEMT amplifier mounted on a small hermetically-sealed package has been developed for use in Advanced Microwave Scanning Radiometer. A six-stage amplifier cascading three two-stage MMIC amplifier chips is assembled on a small hermetically-sealed package with wave guide interface and has achieved a noise figure of 4.3 dB with a gain of 28.1 dB at 91 GHz. The overall amplifier measures 12 x 32.8 x 5.4 mm³. This is the first W-band multi-stage monolithic low noise amplifier mounted on a hermetically-sealed package.

 [Return to main document.](#)